

Supplementary information

Tailoring Microwave Dielectric Properties through High-Entropy Strategy in Spinel-type Titanium Ceramics

Linqiao Zhang^{a,#}, Pingwen Xiang^{a,#}, Yuanming Lai^{a,b,*}, Feng Liu^a, Yuanxun Li^{b,c,d}, Fangyi Huang^e,
Jiao Han^f, Yiming Zeng^f, Qian Liu^a, Chongsheng Wu^a

^a School of Mechanical and Electrical Engineering, Chengdu University of Technology, Chengdu 610059, China

^b State Key Laboratory of Electronic Thin Films and Integrated Devices, University of Electronic Science and Technology of China, Chengdu 610054, China

^c Chengdu Hongke Electronic Technology Co., Ltd, Chengdu 500643, China

^d Ganzhou Yanchuang Electronic Technology Co., Ltd, Ganzhou, 341000, China

^e Key Laboratory of New Processing Technology for Nonferrous Metal and Materials, Ministry of Education, Guangxi Key Laboratory of Optical and Electronic Materials and Devices, Guilin University of Technology, 541004, Guilin, China

^f Yunnan Precious Metals Lab Co.,LTD, Kunming 650106, China

The bulk density of the high-entropy MZLCNT ceramics was measured via the Archimedes method. The theoretical density of the crystalline phase, denoted as ρ_{theo} , was calculated in accordance with equation (1)[1]:

$$\rho_{\text{theo}} = \frac{ZA}{VcN_A} \quad (1)$$

Here Z is the number of molecules in A unit cell, A is the molar molecular weight, Vc is the volume of a unit cell, and N_A is Avogadro's constant.

The relative density (ρ_{relative}) was used to evaluate the densification of the ceramics, which can be calculated by using the following equation (2):

$$\rho_{\text{relative}} = \frac{\rho_{\text{bulk}}}{\rho_{\text{theo}}} \quad (2)$$

The ρ_{bulk} and ρ_{theo} represent bulk density and theoretical density respectively.

These authors contributed equally to this work.

* Corresponding author: laiyuanming19@cdu.edu.cn

Table S1. The bulk density, theoretical density, and relative density of high-entropy MZLCNT ceramics.

x value	0.0	0.1	0.2	0.3	0.4
$P_{\text{bulk}}(\text{g/cm}^3)$	4.283	4.177	4.073	3.964	3.910
$\rho_{\text{theo}}(\text{g/cm}^3)$	4.398	4.280	4.161	4.044	3.985
$\rho_{\text{relative}}(\%)$	97.4	97.6	97.9	98.0	98.1

Table S2. The oxygen vacancy content of high-entropy MZLCNT ceramics

Parameter	$x = 0.0$	$x = 0.2$	$x = 0.4$
Ti ³⁺ 2p _{3/2}	45448	41174	29854
Ti ⁴⁺ 2p _{3/2}	55983	62439	73685
δ (%)	22.4	19.8	14.4

The ionicity (f_i) of the chemical bond μ in high-entropy MZLCNT ceramics are computed by the following equation:

$$f_i^\mu = \frac{(C^\mu)^2}{(E_g^\mu)^2} \quad (3)$$

$$(E_g^\mu)^2 = (E_h^\mu)^2 + (C^\mu)^2 \quad (4)$$

$$E_h^\mu = \frac{39.74}{(d^\mu)^{2.48}} \quad (5)$$

$$C^\mu = 14.4b^\mu e^{(-k_s^\mu r_o^\mu)} \left[\frac{(Z_A^\mu)^*}{r_o^\mu} - \frac{n}{m} \frac{(Z_B^\mu)^*}{r_o^\mu} \right], n \geq m \quad (6)$$

Where E_g^μ represents the average energy gap between molecular orbitals and antibonding molecular orbitals, E_h^μ and C^μ are respectively the homogeneous and heteropolar components of the energy gap. d^μ refers to the bond length of the μ bond, and b^μ is the correction factor. The $e^{(-k_s^\mu r_o^\mu)}$ is the Thomas Fermi shielding factor, $(Z_A^\mu)^*$, and $(Z_B^\mu)^*$ indicate the number of effective valence electrons of A and B.

The lattice energy of different chemical bonds in high-entropy MZLCNT ceramics, calculated using follow equation:

$$U = \sum_{\mu} (U_{bc}^{\mu} + U_{bi}^{\mu}) \quad (7)$$

$$U_{bc}^{\mu} = 2100m \frac{(Z_{+}^{\mu})^{1.64}}{(d^{\mu})^{0.75}} f_c^{\mu} \quad (8)$$

$$U_{bi}^{\mu} = 1270 \frac{(m+n)Z_{+}^{\mu}Z_{-}^{\mu}}{d^{\mu}} \left(1 - \frac{0.4}{d^{\mu}}\right) f_i^{\mu} \quad (9)$$

Where U_{bi}^{μ} and U_{bc}^{μ} represent the lattice energies contributed by ions and covalent contributions respectively. Z_{+}^{μ} and Z_{-}^{μ} indicate the bond valence of the cation and anion in the chemical bond μ .

Table. S3 The bond length, ionicity (f_i), covalency (f_c) and lattice energy of different bond in high-entropy MZLCNT ceramics.

x value	Bond type	Bond length (Å)	f_i (%)	f_c (%)	Lattice energy (kJ/mol)
0.0	A(1)-O	1.90	62.55	37.45	2329
	A(2)-O	2.17	64.76	35.24	1920
	Ti-O	2.17	89.14	10.86	7649
0.1	A(1)-O	1.84	60.64	39.36	2211
	A(2)-O	2.10	63.28	36.72	1971
	Ti-O	2.10	85.74	14.26	7855
0.2	A(1)-O	1.83	62.44	37.56	2204
	A(2)-O	2.09	65.97	34.03	1974
	Ti-O	2.09	85.48	14.52	7865
0.3	A(1)-O	1.87	68.44	31.56	2170
	A(2)-O	2.08	67.36	32.64	1989
	Ti-O	2.08	84.25	15.75	7925
0.4	A(1)-O	1.92	74.73	25.27	2130
	A(2)-O	2.05	75.52	24.48	2010
	Ti-O	2.05	82.57	17.43	8005

The lattice distortion (\mathcal{E}^{W-H}) of high-entropy MZLCNT ceramics can be calculated by the following equation:

$$\mathcal{E}^{W-H} = \frac{\beta_{hkl}}{4\tan(\theta_{hkl})} \quad (10)$$

Where \mathcal{E}^{W-H} , β_{hkl} , and θ_{hkl} represent the lattice distortion, full width at half of the maximum and diffraction angle.

Table S4. The lattice distortion of high-entropy MZLCNT ceramics with $x = 0.0-0.4$.

x value	ΔS_{config}	Peak position ($2\theta_{hkl}$)/ β_{hkl}							\mathcal{E}^{W-H} (%)
		Peak 1	Peak 2	Peak 3	Peak 4	Peak 5	Peak 6	Peak 7	
0.0	1.09R	18.256/ 0.116	30.016/ 0.097	35.338/ 0.100	42.955/ 0.101	53.276/ 0.095	56.782/ 0.105	62.343/ 0.105	1.858
0.1	1.38R	18.244/ 0.120	30.015/ 0.100	35.342/ 0.100	42.955/ 0.108	53.277/ 0.096	56.783/ 0.103	62.356/ 0.109	1.621
0.2	1.52R	18.261/ 0.112	30.020/ 0.104	32.358/ 0.104	42.961/ 0.111	53.284/ 0.100	56.800/ 0.108	62.363/ 0.113	1.034
0.3	1.58R	18.259/ 0.109	30.018/ 0.098	35.356/ 0.103	42.959/ 0.095	52.281/ 0.097	56.798/ 0.098	62.362/ 0.111	1.110
0.4	1.61R	18.256/ 0.131	30.017/ 0.091	35.354/ 0.099	42.957/ 0.094	53.280/ 0.094	56.797/ 0.095	62.359/ 0.090	2.327

The bond strength of the A(1)-O bond in the high-entropy MZLCNT ceramic [AO₄] tetrahedron is calculated by equation (11)[2]:

$$S = S_0 \left(\frac{R_i}{R_0} \right)^{-N} \quad (11)$$

where R_i is the average A-O bond length in the [AO₄] tetrahedra, with N and R_0 representing empirical constants defined by the cation site and cation-anion pair.

Reference

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- [2] I.D. Brown, R.D. Shannon, Empirical Bond-Strength-Bond-Length Curves for Oxides, 1973.